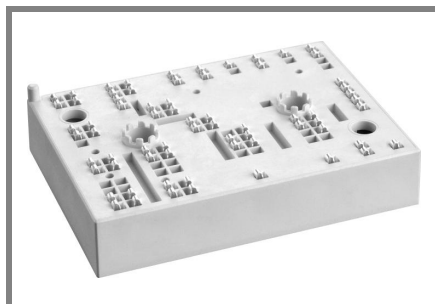


# SKiiP 37AC125V20



## MiniSKiiP® 3

### 3-phase bridge inverter

#### SKiiP 37AC125V20

#### Preliminary Data

#### Features

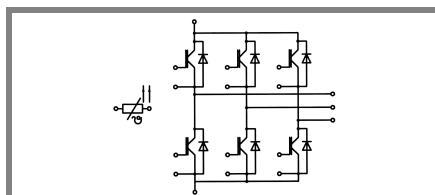
- Ultrafast NPT IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

#### Typical Applications

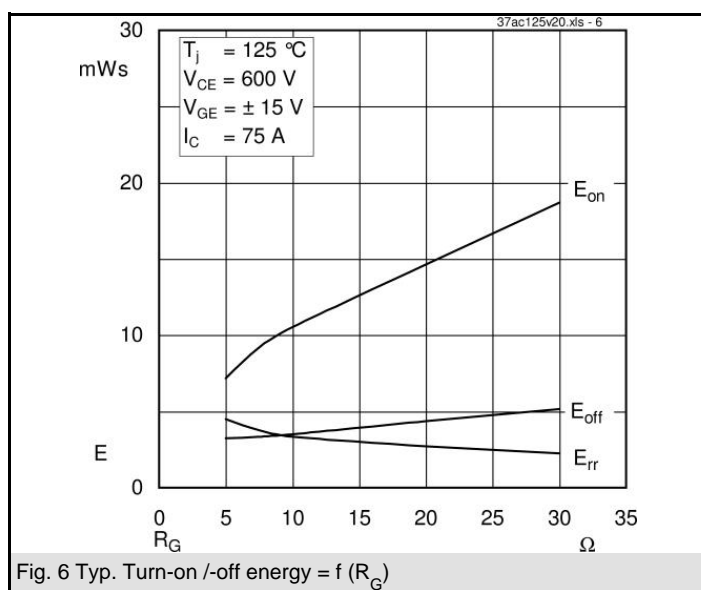
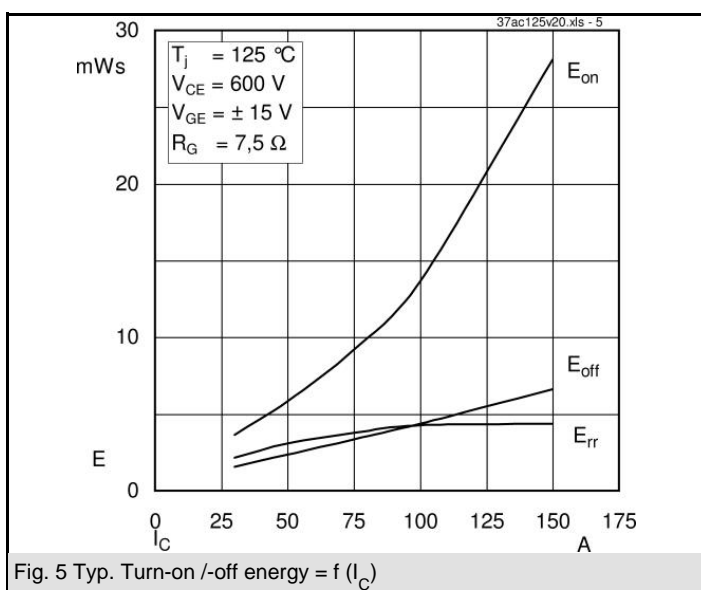
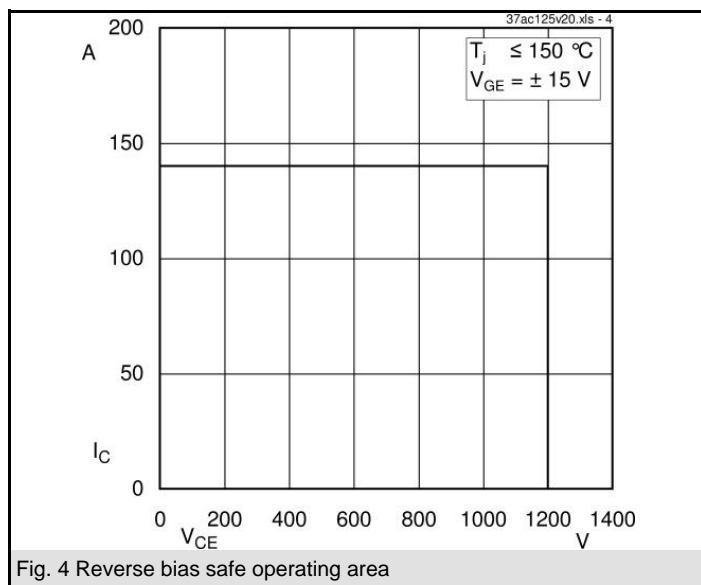
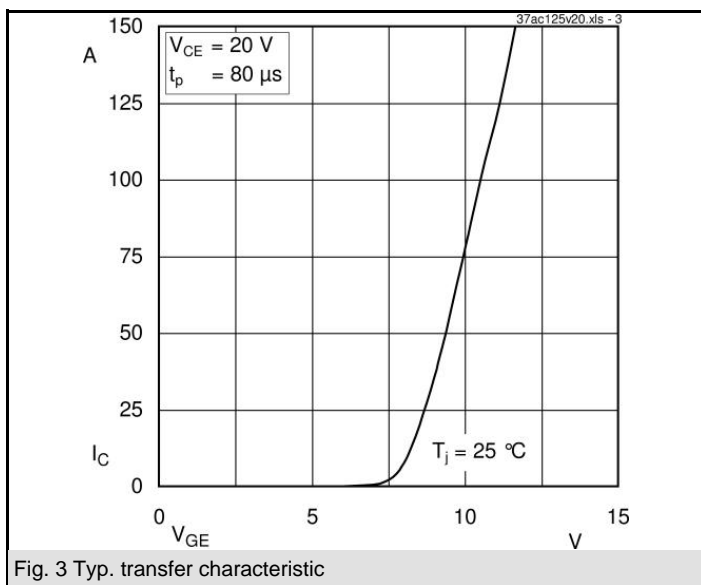
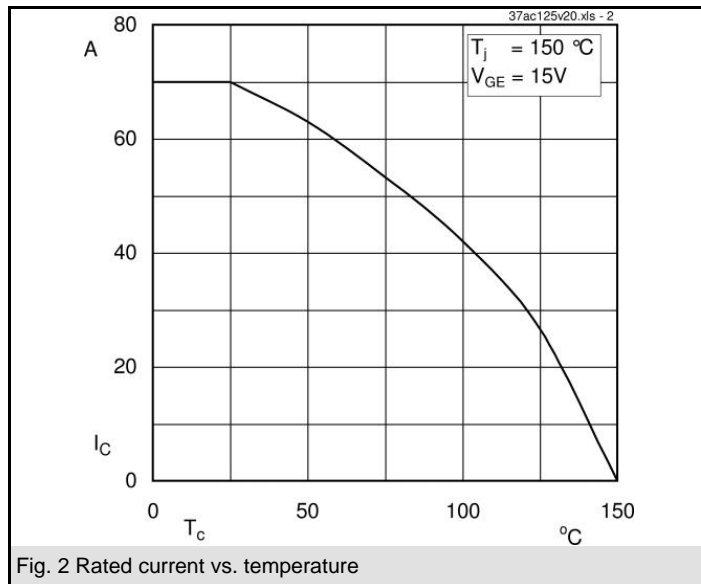
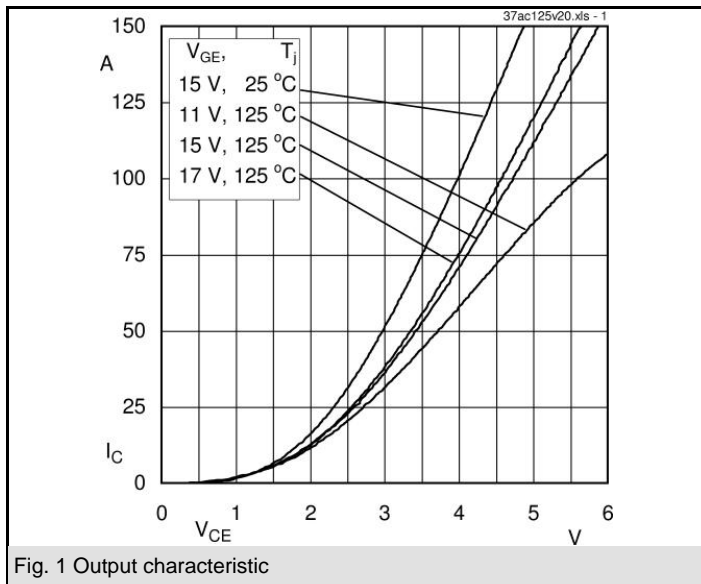
- Inverter up to 30 kVA
- Typical motor power 18,5 kW

Absolute Maximum Ratings		$T_s = 25\text{ °C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT - Inverter</b>			
$V_{CES}$		1200	V
$I_C$	$T_s = 25\text{ (70) °C}$	70 (52)	A
$I_{CRM}$	$T_s = 25\text{ (70) °C}$ , $t_p \leq 1\text{ ms}$	140 (104)	A
$V_{GES}$		$\pm 20$	V
$T_j$		- 40 ... + 150	°C
<b>Diode - Inverter</b>			
$I_F$	$T_s = 25\text{ (70) °C}$	91 (68)	A
$I_{FRM}$	$T_s = 25\text{ (70) °C}$ , $t_p \leq 1\text{ ms}$	182 (136)	A
$T_j$		- 40 ... + 150	°C
$I_{tRMS}$	per power terminal (20 A / spring)	160	A
$T_{stg}$	$T_{op} \leq T_{stg}$	- 40 ... + 125	°C
$V_{isol}$	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ °C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT - Inverter</b>					
$V_{CEsat}$	$I_C = 75\text{ A}$ , $T_j = 25\text{ (125) °C}$		3,5 (4,1)	3,9 (4,5)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 3\text{ mA}$	4,5	5,5	6,5	V
$V_{CE(TO)}$	$T_j = 25\text{ (125) °C}$		1,5 (1,8)	1,7 (2)	V
$r_T$	$T_j = 25\text{ (125) °C}$		40 (46)	44 (50)	mΩ
$C_{ies}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		4,7		nF
$C_{oes}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		0,6		nF
$C_{res}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		0,6		nF
$R_{th(j-s)}$	per IGBT		0,4		K/W
$t_{d(on)}$	under following conditions		30		ns
$t_r$	$V_{CC} = 600\text{ V}$ , $V_{GE} = \pm 15\text{ V}$		40		ns
$t_{d(off)}$	$I_C = 75\text{ A}$ , $T_j = 125\text{ °C}$		250		ns
$t_f$	$R_{Gon} = R_{Goff} = 7,5\text{ Ω}$		30		ns
$E_{on}$	inductive load		9,2		mJ
$E_{off}$			3,3		mJ
<b>Diode - Inverter</b>					
$V_F = V_{EC}$	$I_F = 75\text{ A}$ , $T_j = 25\text{ (125) °C}$		2 (1,8)	2,5 (2,3)	V
$V_{(TO)}$	$T_j = 25\text{ (125) °C}$		1,3 (1)	1,5 (1,2)	V
$r_T$	$T_j = 25\text{ (125) °C}$		14 (16)	20 (22)	mΩ
$R_{th(j-s)}$	per diode		0,55		K/W
$I_{RRM}$	under following conditions		94		A
$Q_{rr}$	$I_F = 75\text{ A}$ , $V_R = 600\text{ V}$		11		μC
$E_{rr}$	$V_{GE} = 0\text{ V}$ , $T_j = 125\text{ °C}$ $di_F/dt = 2850\text{ A/μs}$		3,8		mJ
<b>Temperature Sensor</b>					
$R_{ts}$	3 %, $T_r = 25\text{ (100) °C}$		1000(1670)		Ω
<b>Mechanical Data</b>					
m			95		g
$M_s$	Mounting torque	2		2,5	Nm



AC



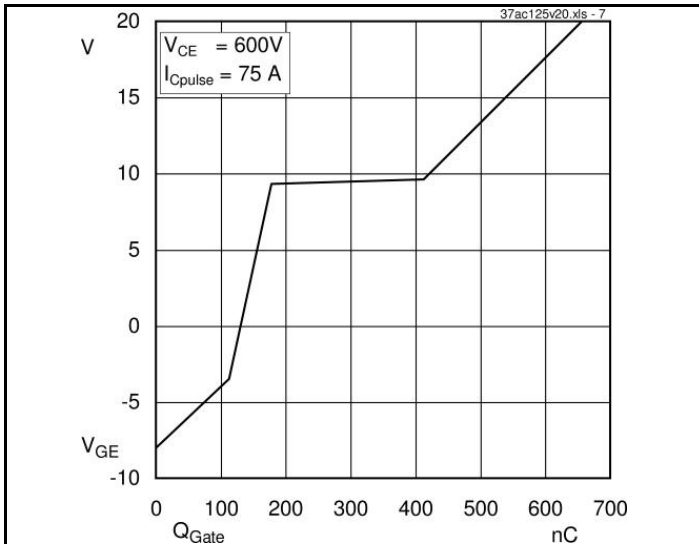


Fig. 7 Typ. gate charge characteristic

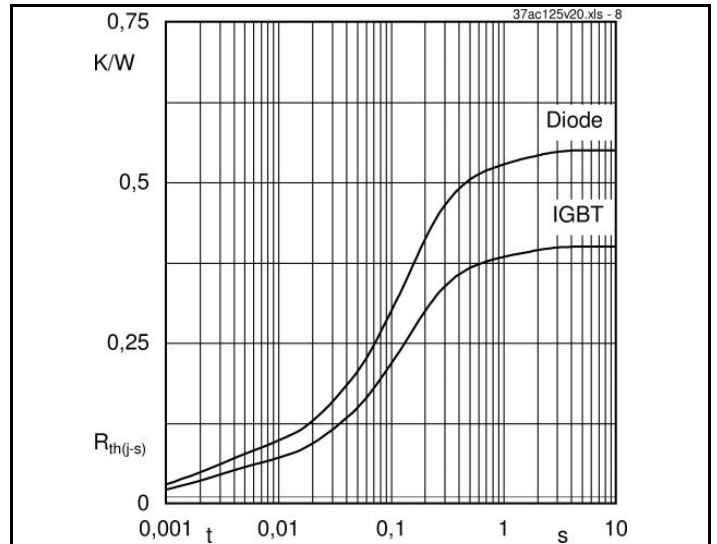


Fig. 8 Typ. thermal impedance

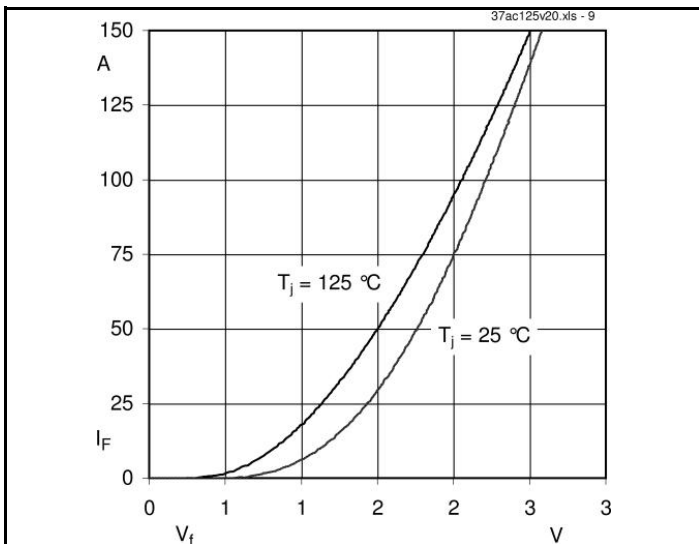
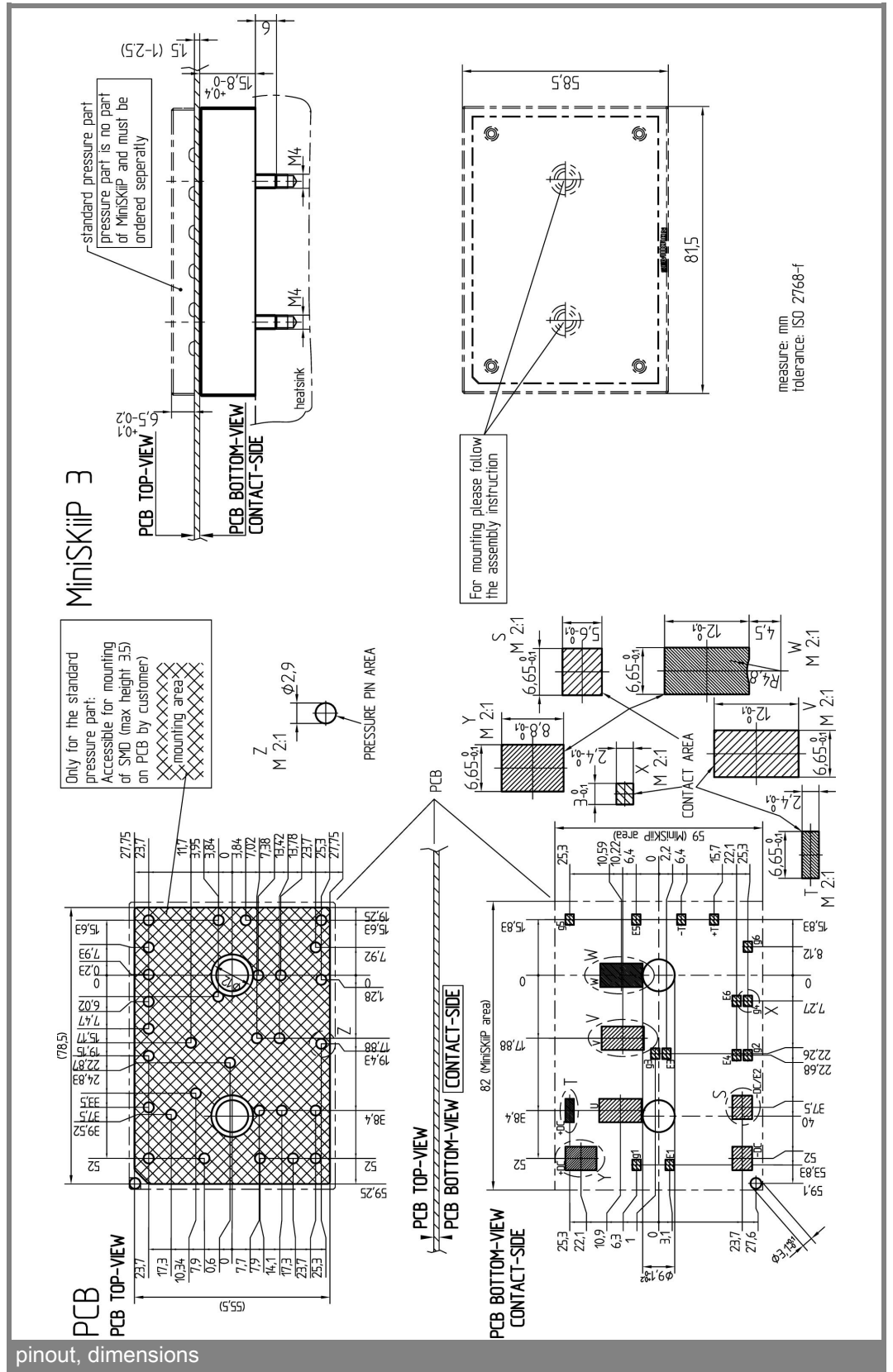
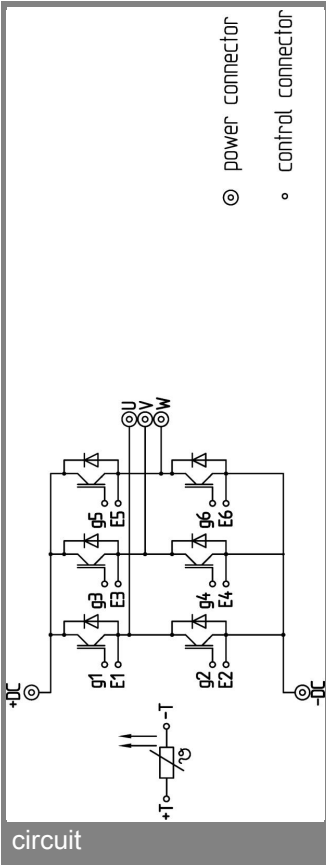


Fig. 9 Typ. freewheeling diode forward characteristic



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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